

# New Jersey Semi-Conductor Products, Inc.

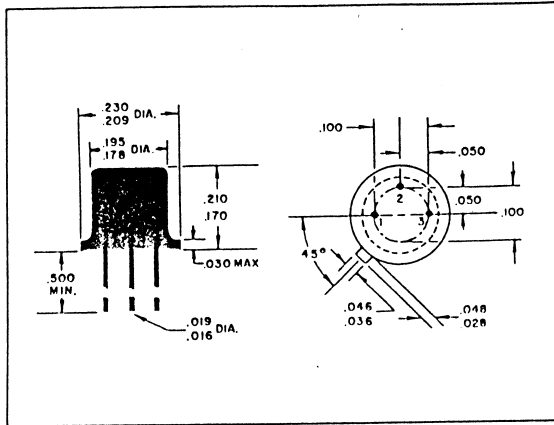
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## NPN SMALL SIGNAL GENERAL PURPOSE AMPLIFIER AND SWITCH

### MECHANICAL DATA

CASE: JEDEC TO-18  
 TERMINAL CONNECTIONS:  
 Lead 1 Emitter      Lead 2 Base  
 Lead 3 Collector (Electrically connected to case)



# 2N2222

### ELECTRICAL DATA

#### ABSOLUTE MAXIMUM RATINGS:

Collector to Base Voltage $V_{CRO}$	60 volts
Collector to Emitter Voltage $V_{CEO}$	30 volts
Emitter to Base Voltage $V_{ERO}$	5 volts
Total Device Dissipation	
@ Case Temperature 25° C	1.8 watts
@ Case Temperature 100° C	0.9 watts
@ Free Air Temperature 25° C	0.5 watts
Junction Temperature (Operating)	-65° C to +175° C
Storage Temperature	-65° C to +300° C

#### ELECTRICAL CHARACTERISTICS: @25° C (unless otherwise noted)

PARAMETER	SYM.	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Collector to Base Breakdown Voltage	$BV_{CBO}$	$I_C=10 \mu A$	60	....	....	volts
Collector to Emitter Breakdown Voltage ▲	$BV_{CEO}$	$I_C=10 mA$	30	....	....	volts
Emitter to Base Breakdown Voltage	$BV_{EBO}$	$I_E=10 \mu A$	5	....	....	volts
Collector Cutoff Current	$I_{CBO1}$	$V_{CB}=50 V$	....	....	10	nA
Collector Cutoff Current	$I_{CBO2}$	$V_{CB}=50 V, T_A=+150^\circ C$	....	....	10	$\mu A$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=3 V$	....	....	10	nA
DC Current Gain	$h_{FE1}$	$V_{CE}=10 V, I_C=0.1 mA$	35	55	....	....
DC Current Gain	$h_{FE2}$	$V_{CE}=10 V, I_C=1.0 mA$	50	100	....	....
DC Current Gain ▲	$h_{FE3}$	$V_{CE}=10 V, I_C=10 mA$	75	150	....	....
DC Current Gain ▲	$h_{FE4}$	$V_{CE}=10 V, I_C=150 mA$	100	200	300	....
DC Current Gain ▲	$h_{FE5}$	$V_{CE}=10 V, I_C=500 mA$	30	65	....	....
DC Current Gain ▲	$h_{FE6}$	$V_{CE}=1 V, I_C=150 mA$	50	90	....	....
Collector to Emitter Saturation Voltage ▲	$V_{CE(sat) 1}$	$I_C=150 mA, I_B=15 mA$	....	0.2	0.4	volts
Collector to Emitter Saturation Voltage ▲	$V_{CE(sat) 2}$	$I_C=500 mA, I_B=50 mA$	....	0.5	1.6	volts
Base to Emitter Saturation Voltage ▲	$V_{BE(sat) 1}$	$I_C=150 mA, I_B=15 mA$	....	1.1	1.3	volts
Base to Emitter Saturation Voltage ▲	$V_{BE(sat) 2}$	$I_C=500 mA, I_B=50 mA$	....	1.5	2.6	volts
High Frequency Small Signal Current Gain	$h_{fe}$	$V_{CE}=20 V, I_C=20 mA, f=100 mc$	2.5	3.5	....	....
Collector Capacitance	$C_{ob}$	$V_{CB}=10 V, I_E=0 mA$	....	7	8	pf
Current Gain-Bandwidth Product	$f_T$	$V_{CE}=20 V, I_C=20 mA, f=100 mc$	250	350	....	mc
Real Part of Input Impedance	$Re(h_{ie})$	$V_{CE}=20 V, I_C=20 mA$	....	....	60	ohms